2.5-V PHASE-LOCKED-LOOP CLOCK DRIVER

FEATURES

- **Spread-Spectrum Clock Compatible**
- **Operating Frequency: 60 MHz to 220 MHz**
- **Low Jitter (Cycle-Cycle): ±60 ps (±40 ps at 200 MHz)**
- **Low Static Phase Offset: ±50 ps**
- **Low Jitter (Period): ±60 ps (±30 ps at 200 MHz)**
- **1-to-4 Differential Clock Distribution (SSTL2)**
- **Best in Class for $V_{OX} = V_{DD}/2$ ±0.1 V**
- **Operates From Dual 2.6-V or 2.5-V Supplies**
- **Available in a 28-Pin TSSOP Package**
- **Consumes < 100-μA Quiescent Current**
- **External Feedback Pins (FBIN, $\overline{\text{FBIN}}$) Are Used to Synchronize the Outputs to the Input Clocks**
- **Meets/Exceeds JEDEC Standard (JESD82-1) For DDRI-200/266/333 Specification**
- **Meets/Exceeds Proposed DDRI-400 Specification (JESD82-1A)**
- **Enters Low-Power Mode When No CLK Input Signal Is Applied or $\overline{\text{PWRDWN}}$ Is Low**

APPLICATIONS

- **DDR Memory Modules (DDR400/333/266/200)**
- **Zero-Delay Fan-Out Buffer**

DESCRIPTION

The CDCVF855 is a high-performance, low-skew, low-jitter, zero-delay buffer that distributes a differential clock input pair (CLK, $\overline{\text{CLK}}$) to 4 differential pairs of clock outputs (Y[0:3], $\overline{\text{Y[0:3]}}$) and one differential pair of feedback clock outputs (FBOUT, $\overline{\text{FBOUT}}$). The clock outputs are controlled by the clock inputs (CLK, $\overline{\text{CLK}}$), the feedback clocks (FBIN, $\overline{\text{FBIN}}$), and the analog power input (AV_{DD}). When $\overline{\text{PWRDWN}}$ is high, the outputs switch in phase and frequency with CLK. When $\overline{\text{PWRDWN}}$ is low, all outputs are disabled to a high-impedance state (3-state) and the PLL is shut down (low-power mode). The device also enters this low-power mode when the input frequency falls below a suggested detection frequency that is below 20 MHz (typical 10 MHz). An input frequency-detection circuit detects the low-frequency condition and, after applying a >20-MHz input signal, this detection circuit turns the PLL on and enables the outputs.

When AV_{DD} is strapped low, the PLL is turned off and bypassed for test purposes. The CDCVF855 is also able to track spread-spectrum clocking for reduced EMI.

Because the CDCVF855 is based on PLL circuitry, it requires a stabilization time to achieve phase-lock of the PLL. This stabilization time is required following power up. The CDCVF855 is characterized for both commercial and industrial temperature ranges.

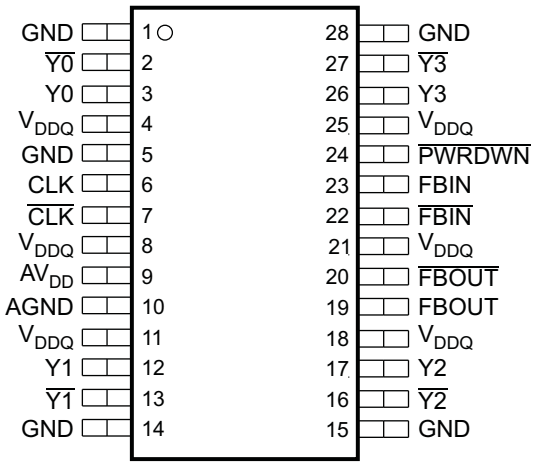
AVAILABLE OPTIONS

T_A	TSSOP (PW)
–40°C to 85°C	CDCVF855PW

FUNCTION TABLE
(Select Functions)

INPUTS				OUTPUTS				PLL
AVDD	$\overline{\text{PWRDWN}}$	CLK	$\overline{\text{CLK}}$	Y[0:3]	$\overline{\text{Y[0:3]}}$	FBOUT	$\overline{\text{FBOUT}}$	
GND	H	L	H	L	H	L	H	Bypassed/off
GND	H	H	L	H	L	H	L	Bypassed/off
X	L	L	H	Z	Z	Z	Z	Off
X	L	H	L	Z	Z	Z	Z	Off
2.5 V (nom)	H	L	H	L	H	L	H	Off
2.5 V (nom)	H	H	L	H	L	H	L	Off
2.5 V (nom)	X	<20 MHz	<20 MHz	Z	Z	Z	Z	Off

PWP PACKAGE
(TOP VIEW)



P0043-02

FUNCTIONAL BLOCK DIAGRAM

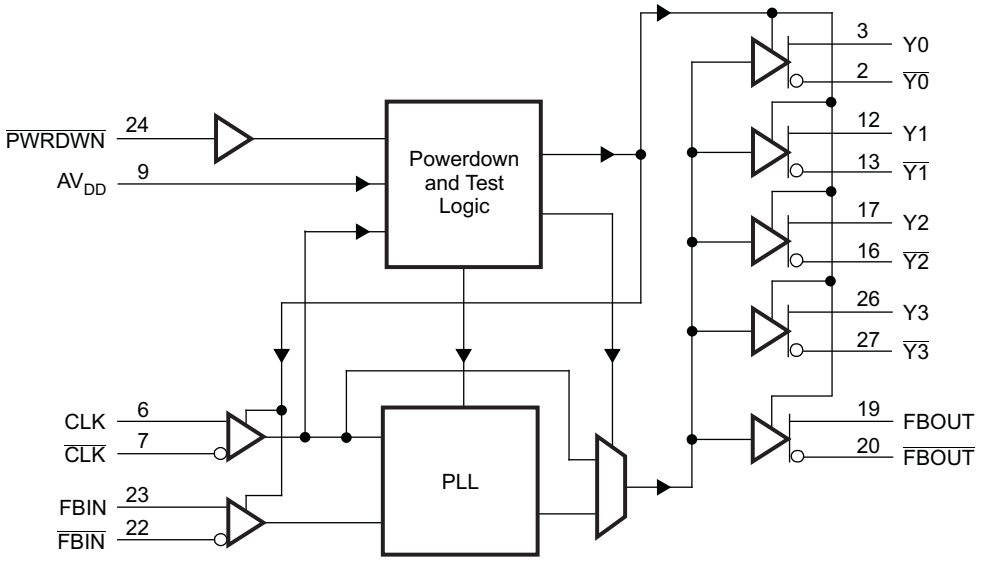


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Table 2. TERMINAL FUNCTIONS

TERMINAL		I/O	DESCRIPTION
NAME	NO.		
AGND	10	–	Ground for 2.5-V analog supply
AV_{DD}	9	–	2.5-V analog supply
CLK, $\overline{CLK}$	6, 7	I	Differential clock input
$\overline{FBIN}$, FBIN	22, 23	I	Feedback differential clock input
FBOUT, $\overline{FBOUT}$	19, 20	O	Feedback differential clock output
GND	1, 5, 14, 15, 28	–	Ground
$\overline{PWRDWN}$	24	I	Output enable for Y and $\overline{Y}$
V_{DDQ}	4, 8, 11, 18, 21, 25	–	2.5-V supply
$\overline{Y0}$, Y0	2, 3	O	Buffered output copies of input clock, CLK, $\overline{CLK}$
Y1, $\overline{Y1}$	12, 13	O	Buffered output copies of input clock, CLK, $\overline{CLK}$
$\overline{Y2}$, Y2	16, 17	O	Buffered output copies of input clock, CLK, $\overline{CLK}$
Y3, $\overline{Y3}$	26, 27	O	Buffered output copies of input clock, CLK, $\overline{CLK}$

ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range (unless otherwise noted) (1)

V_{DDQ}, AV_{DD}	Supply voltage range		0.5 V to 3.6 V
V_I	Input voltage range (2) (3)		–0.5 V to V_{DDQ} + 0.5 V
V_O	Output voltage range (2) (3)		–0.5 V to V_{DDQ} + 0.5 V
I_{IK}	Input clamp current	$V_I < 0$ or $V_I > V_{DDQ}$	±50 mA
I_{OK}	Output clamp current	$V_O < 0$ or $V_O > V_{DDQ}$	±50 mA
I_O	Continuous output current	V_O = 0 to V_{DDQ}	±50 mA
I_{DDS}	Continuous current to GND or V_{DDQ}		±100 mA
T_{stg}	Storage temperature range		–65°C to 150°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.
(3) This value is limited to 3.6 V maximum.

THERMAL CHARACTERISTICS

$R_{\theta JA}$ for TSSOP Package (1)	
Airflow	High K
0 ft/min (0 m/min)	94.4°C/W
150 ft/min (45.72 m/min)	82.8°C/W

(1) The package thermal impedance is calculated in accordance with JESD 51.

RECOMMENDED OPERATING CONDITIONS

					MIN	NOM	MAX	UNIT
	Supply voltage	V_{DDQ}	PC1600 – PC3200		2.3		2.7	V
		AVDD			V_{DDQ} – 0.12		2.7	
V_{IL}	Low-level input voltage	CLK, $\overline{CLK}$, FBIN, $\overline{FBIN}$					$V_{DDQ}/2$ – 0.18	V
		$\overline{PWRDWN}$			–0.3		0.7	
V_{IH}	High-level input voltage	CLK, $\overline{CLK}$, FBIN, $\overline{FBIN}$			$V_{DDQ}/2$ + 0.18			V
		$\overline{PWRDWN}$			1.7		V_{DDQ} + 0.3	
	DC input signal voltage(1)				–0.3		V_{DDQ} + 0.3	V
V_{ID}	Differential input signal voltage(2)	DC	CLK, FBIN	V_{DDQ} = 2.3 V – 2.7V	0.36		V_{DDQ} + 0.6	V
				V_{DDQ} = 2.425 V – 2.7 V	0.25		V_{DDQ} + 0.6	
		AC	CLK, FBIN	V_{DDQ} = 2.3 V – 2.7 V	0.7		V_{DDQ} + 0.6	
				V_{DDQ} = 2.425 V – 2.7 V	0.49		V_{DDQ} + 0.6	
V_{IX}	Input differential pair cross voltage(3)(4)				$V_{DDQ}/2$ – 0.2		$V_{DDQ}/2$ + 0.2	V
I_{OH}	High-level output current						–12	mA
I_{OL}	Low-level output current						12	mA
SR	Input slew rate				1		4	V/ns
T_A	Operating free-air temperature				–40		85	°C

(1) The unused inputs must be held high or low to prevent them from floating.
(2) The dc input signal voltage specifies the allowable dc execution of the differential input.
(3) The differential input signal voltage specifies the differential voltage |VTR – VCP| required for switching, where VTR is the true input level and VCP is the complementary input level.
(4) The differential cross-point voltage is expected to track variations of V_{CC} and is the voltage at which the differential signals must cross.

ELECTRICAL CHARACTERISTICS

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP (1)	MAX	UNIT
V_{IK}	Input voltage, all inputs	V_{DDQ} = 2.3 V, I_I = –18 mA			–1.2	V
V_{OH}	High-level output voltage	V_{DDQ} = min to max, I_{OH} = –1 mA	V_{DDQ} – 0.1			V
		V_{DDQ} = 2.3 V, I_{OH} = –12 mA	1.7			
V_{OL}	Low-level output voltage	V_{DDQ} = min to max, I_{OL} = 1 mA			0.1	V
		V_{DDQ} = 2.3 V, I_{OL} = 12 mA			0.6	
V_{OD}	Output voltage swing (2)	Differential outputs are terminated with 120 Ω, C_L = 14 pF (See Figure 3)	1.1		V_{DDQ} – 0.4	V
V_{OX}	Output differential cross-voltage (3)		$V_{DDQ}/2$ – 0.1	$V_{DDQ}/2$	$V_{DDQ}/2$ + 0.1	V
I_I	Input current	V_{DDQ} = 2.7 V, V_I = 0 V to 2.7 V			±10	µA
I_{OZ}	High-impedance-state output current	V_{DDQ} = 2.7 V, V_O = V_{DDQ} or GND			±10	µA
I_{DDPD}	Power-down current on V_{DDQ} + AV_{DD}	CLK and $\overline{CLK}$ = 0 MHz; $\overline{PWRDWN}$ = Low; Σ of I_{DD} and AI_{DD}		20	100	µA
AI_{DD}	Supply current on AV_{DD}	f_O = 170 MHz		6	8	mA
		f_O = 200 MHz		8	10	
C_I	Input capacitance	V_{DDQ} = 2.5 V, V_I = V_{DDQ} or GND	2	2.5	3.5	pF

(1) All typical values are at a nominal V_{DDQ}.
(2) The differential output signal voltage specifies the differential voltage |VTR – VCP|, where VTR is the true output level and VCP is the complementary output level.
(3) The differential cross-point voltage tracks variations of V_{DDQ} and is the voltage at which the differential signals must cross.

ELECTRICAL CHARACTERISTICS (continued)

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP (1)	MAX	UNIT
I_{DD}	Dynamic current on V_{DDQ}	Without load	f_O = 170 MHz		65	80	mA
			f_O = 200 MHz		75	90	
		Differential outputs terminated with 120 Ω, C_L = 0 pF	f_O = 170 MHz		110	140	
			f_O = 200 MHz		120	150	
		Differential outputs terminated with 120 Ω, C_L = 14 pF	f_O = 170 MHz		130	160	
			f_O = 200 MHz		140	170	
ΔC	Part-to-part input capacitance variation	V_{DDQ} = 2.5 V, V_I = V_{DDQ} or GND				1	pF
$C_{I(Δ)}$	Input capacitance difference between CLK and $\overline{CLK}$, FBIN and $\overline{FBIN}$	V_{DDQ} = 2.5 V, V_I = V_{DDQ} or GND				0.25	pF

TIMING REQUIREMENTS

over recommended ranges of supply voltage and operating free-air temperature

PARAMETER		MIN	MAX	UNIT
f_{CLK}	Operating clock frequency	60	220	MHz
	Application clock frequency	90	220	
	Input clock duty cycle	40%	60%	
	Stabilization time (PLL mode)(1)		10	µs
	Stabilization time (bypass mode)(2)		30	ns

(1) The time required for the integrated PLL circuit to obtain phase lock of its feedback signal to its reference signal. For phase lock to be obtained, a fixed-frequency, fixed-phase reference signal must be present at CLK and V_{DD} must be applied. Until phase lock is obtained, the specifications for propagation delay, skew, and jitter parameters given in the switching characteristics table are not applicable. This parameter does not apply for input modulation under SSC application.

(2) A recovery time is required when the device goes from power-down mode into bypass mode (AV_{DD} at GND).

SWITCHING CHARACTERISTICS

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
t_{PLH} (1)	Low- to high-level propagation delay time	Test mode/CLK to any output		3.5		ns
t_{PHL} (1)	High- to low-level propagation delay time	Test mode/CLK to any output		3.5		ns
$t_{jit(per)}$ (2)	Jitter (period), see Figure 7	100/133/167 MHz (PC1600/2100/2700)	–65		65	ps
		200 MHz (PC3200)	–30		30	
$t_{jit(cc)}$ (2)	Jitter (cycle-to-cycle), see Figure 4	100/133/167 MHz (PC1600/2100/2700)	–60		60	ps
		200 MHz (PC3200)	–40		40	
$t_{jit(hper)}$ (2)	Half-period jitter, see Figure 8	100/133/167 MHz (PC1600/2100/2700)	–100		100	ps
		200 MHz (PC3200)	–75		75	
$t_{slr(o)}$	Output clock slew rate, see Figure 9	Load: 120 Ω, 14 pF	1		2	V/ns
$t_{(\phi)}$	Static phase offset, see Figure 5	100/133/167/200 MHz	–50		50	ps
$t_{sk(o)}$	Output skew, see Figure 6	Load: 120 Ω, 14 pF; 100/133/167/200 MHz			40	ps

(1) Refers to the transition of the noninverting output.
(2) This parameter is assured by design but cannot be 100% production tested.

PARAMETER MEASUREMENT INFORMATION

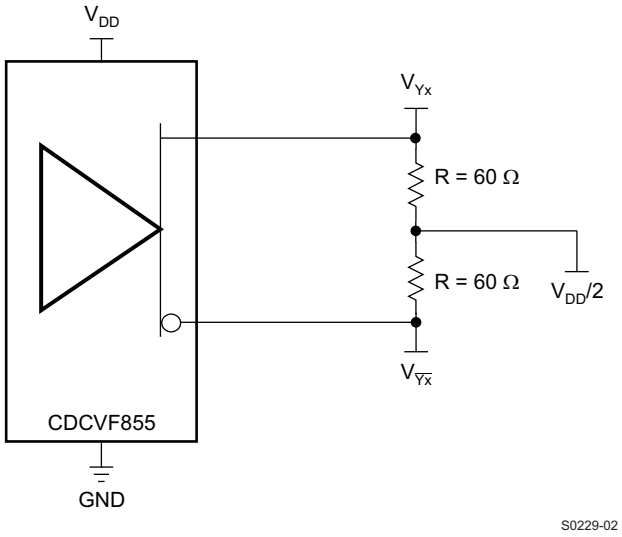


Figure 1. IBIS Model Output Load

PARAMETER MEASUREMENT INFORMATION (continued)

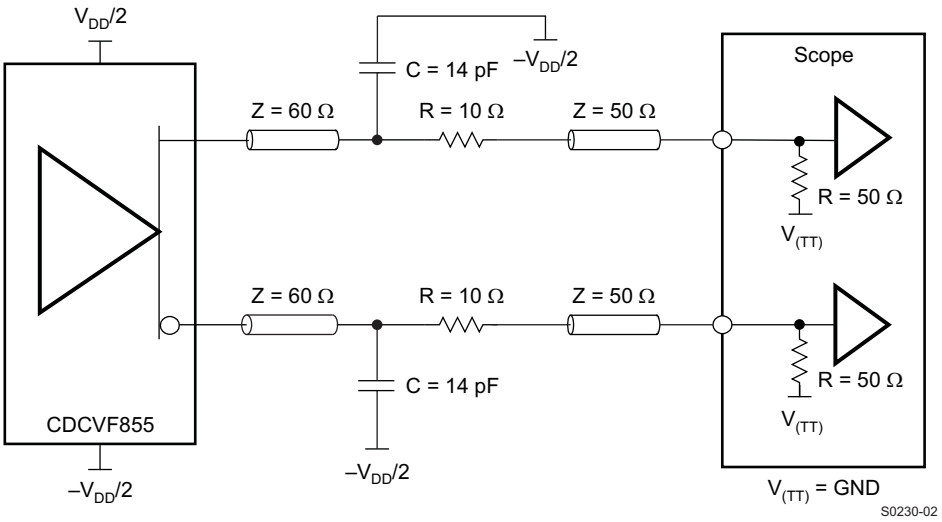


Figure 2. Output Load Test Circuit

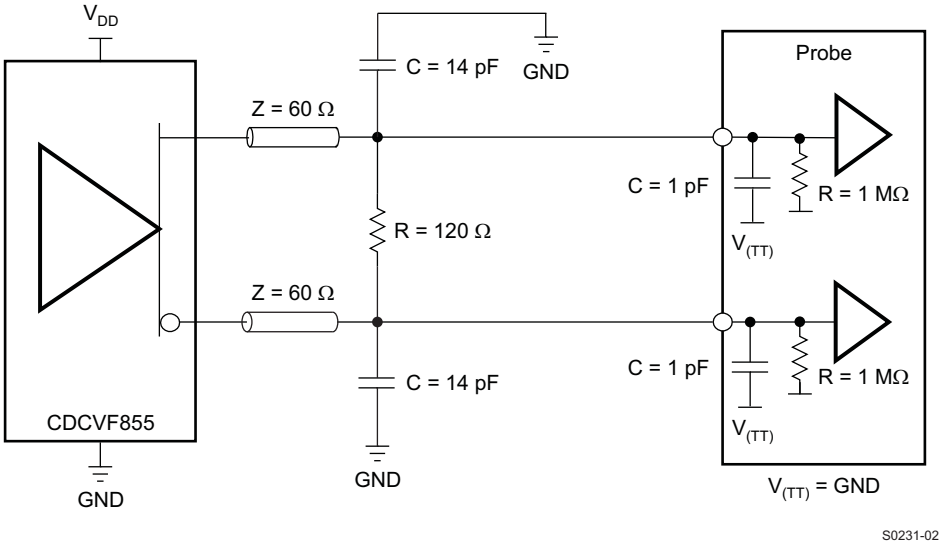


Figure 3. Output Load Test Circuit for Crossing Point

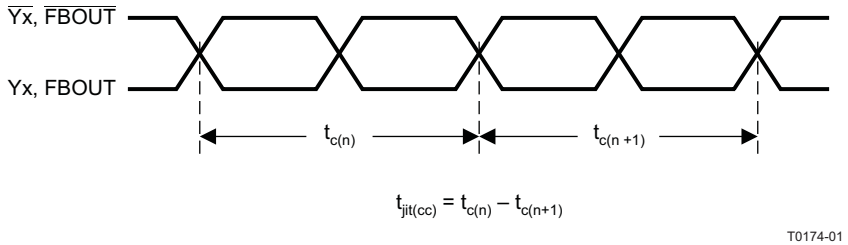
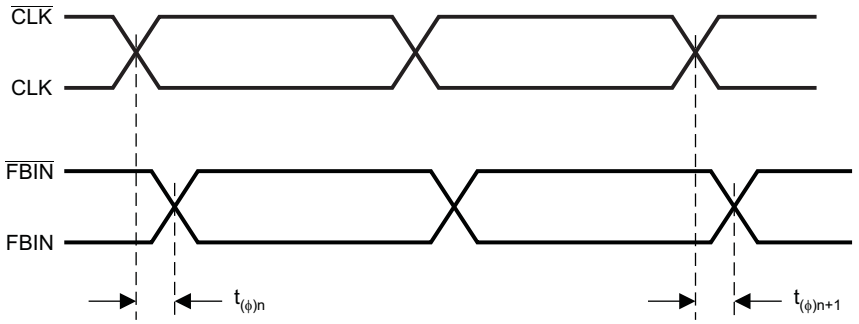


Figure 4. Cycle-to-Cycle Jitter

PARAMETER MEASUREMENT INFORMATION (continued)

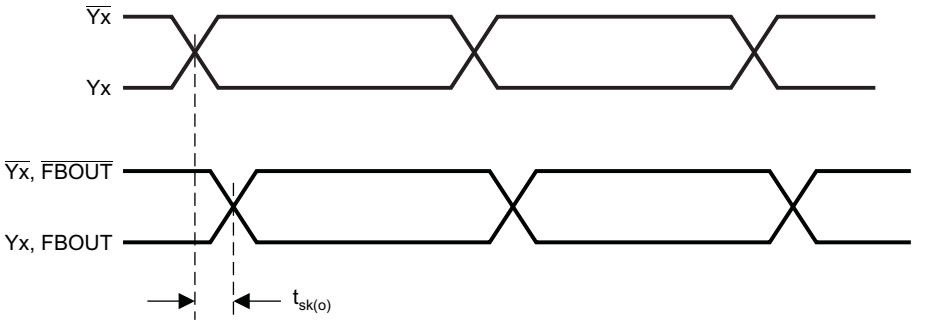


$$t_{(\phi)} = \frac{\sum_{1}^{n=N} t_{(\phi)n}}{N}$$

(N > 1000 Samples)

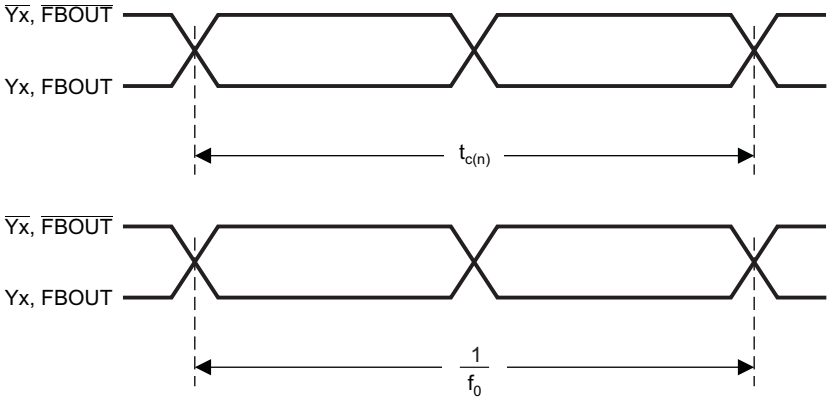
T0175-01

Figure 5. Phase Offset



T0176-01

Figure 6. Output Skew

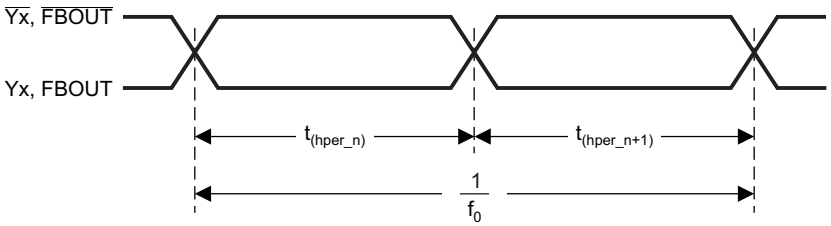


$t_{jit(per)} = t_{c(n)} - \frac{1}{f_0}$ f_0 = Average Input Frequency Measured at CLK/$\overline{CLK}$

T0177-01

Figure 7. Period Jitter

PARAMETER MEASUREMENT INFORMATION (continued)



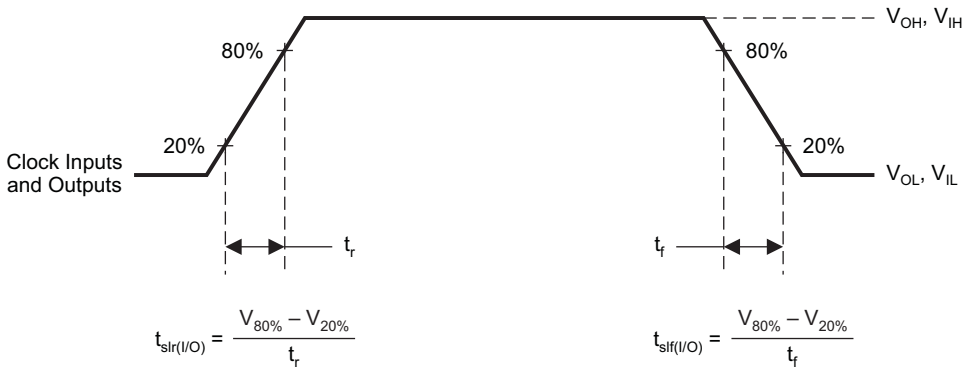
$$t_{jit(hper)} = t_{(hper\_n)} - \frac{1}{2 \times f_0}$$

n = Any Half Cycle

f_0 = Average Input Frequency Measured at CLK/$\overline{CLK}$

T0178-01

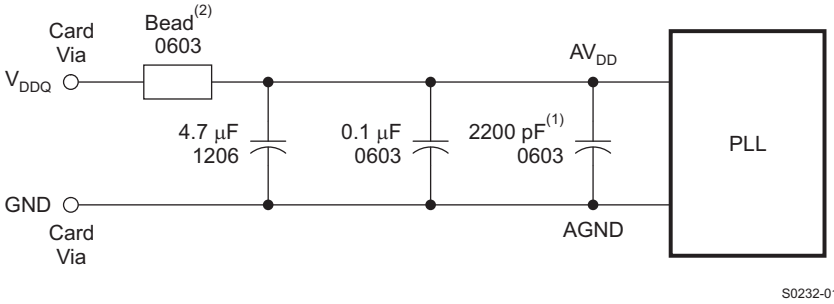
Figure 8. Half-Period Jitter



$$t_{slr(I/O)} = \frac{V_{80\%} - V_{20\%}}{t_r} \qquad t_{slf(I/O)} = \frac{V_{80\%} - V_{20\%}}{t_f}$$

T0179-01

Figure 9. Input and Output Slew Rates



S0232-01

(1) Place the 2200-pF capacitor close to the PLL.

(2) Recommended bead: Fair-Rite P/N 2506036017Y0 or equilvalent (0.8 Ω dc maximum, 600 Ω at 100 MHz).

NOTE: Use a wide trace for the PLL analog power and ground. Connect PLL and capacitors to AGND trace and connect trace to one GND via (farthest from the PLL).

Figure 10. Recommended AV_{DD} Filtering

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)
CDCVF855PW	ACTIVE	TSSOP	PW	28	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CDCVF855PWR	ACTIVE	TSSOP	PW	28	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

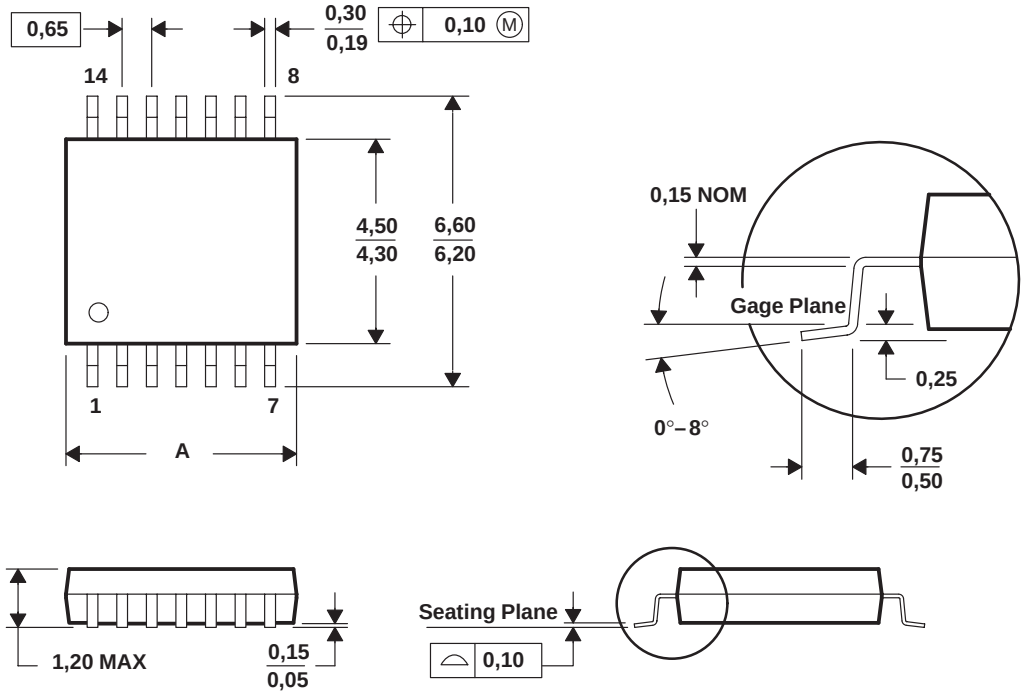
(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.
TBD: The Pb-Free/Green conversion plan has not been defined.
Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.
Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.
Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

PW (R-PDSO-G)** **PLASTIC SMALL-OUTLINE PACKAGE**

14 PINS SHOWN



DIM \ PINS **	8	14	16	20	24	28
A MAX	3,10	5,10	5,10	6,60	7,90	9,80
A MIN	2,90	4,90	4,90	6,40	7,70	9,60

4040064/F 01/97

NOTES: A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
D. Falls within JEDEC MO-153

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